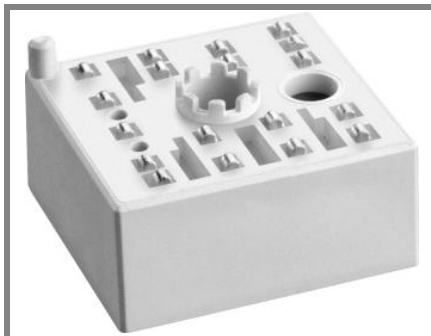


# SKiiP 01NEB066V1



MiniSKiiP® 0

1-phase bridge rectifier +  
brake chopper + 3-phase  
bridge inverter  
**SKiiP 01NEB066V1**

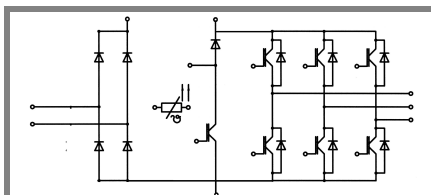
Target Data

## Features

- Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

## Typical Applications

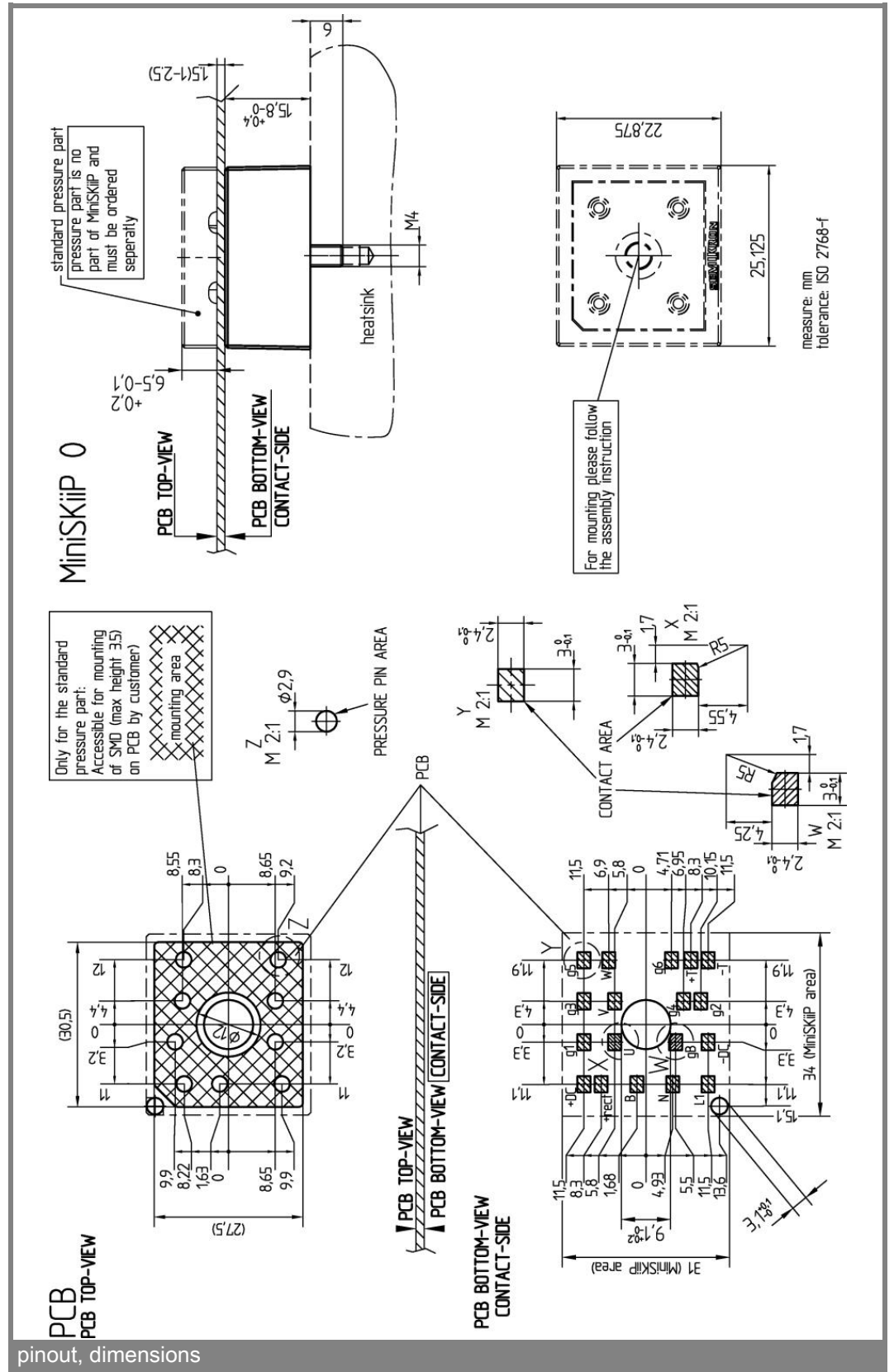
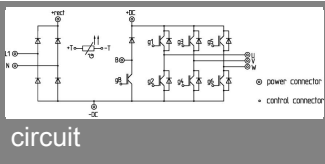
- Inverter up to 3,5 kVA
- Typical motor power 1,5 kW



NEB

Absolute Maximum Ratings		$T_s = 25\text{ °C}$ , unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT - Inverter, Chopper</b>			
$V_{CES}$		600	V
$I_C$	$T_s = 25\text{ (70) °C}$	13 (10)	A
$I_{CRM}$	$T_s = 25\text{ (70) °C}$ , $t_p \leq 1\text{ ms}$	14 (11)	A
$V_{GES}$		$\pm 20$	V
$T_j$		- 40 ... + 175	°C
<b>Diode - Inverter, Chopper</b>			
$I_F$	$T_s = 25\text{ (70) °C}$	15 (11)	A
$I_{FRM}$	$T_s = 25\text{ (70) °C}$ , $t_p \leq 1\text{ ms}$	16 (13)	A
$T_j$		- 40 ... + 175	°C
<b>Diode - Rectifier</b>			
$V_{RRM}$		800	V
$I_F$	$T_s = 70\text{ °C}$	35	A
$I_{FSM}$	$t_p = 10\text{ ms}$ , $\sin 180\text{ °}$ , $T_j = 25\text{ °C}$	220	A
$i^2t$	$t_p = 10\text{ ms}$ , $\sin 180\text{ °}$ , $T_j = 25\text{ °C}$	240	A <sup>2</sup> s
$T_j$		- 40 ... + 150	°C
$I_{tRMS}$	per power terminal (20 A / spring)	20	A
$T_{stg}$	$T_{op} \leq T_{stg}$	- 40 ... + 125	°C
$V_{isol}$	AC, 1 min.	2500	V

Characteristics		$T_s = 25\text{ °C}$ , unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
<b>IGBT - Inverter, Chopper</b>					
$V_{CEsat}$	$I_C = 6\text{ A}$ , $T_j = 25\text{ (125) °C}$	1,1	1,45 (1,65)	1,85 (2,05)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}$ , $I_C = 0,5\text{ mA}$		5,8		V
$V_{CE(TO)}$	$T_j = 25\text{ (125) °C}$		0,9 (0,7)	1,1 (1)	V
$r_T$	$T_j = 25\text{ (125) °C}$		100 (167)	134 (184)	mΩ
$C_{ies}$	$V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$		0,45		nF
$C_{oes}$	$V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$		0,1		nF
$C_{res}$	$V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$		0,05		nF
$R_{th(j-s)}$	per IGBT		2,4		K/W
$t_{d(on)}$	under following conditions		20		ns
$t_r$	$V_{CC} = 300\text{ V}$ , $V_{GE} = \pm 15\text{ V}$		25		ns
$t_{d(off)}$	$I_C = 6\text{ A}$ , $T_j = 125\text{ °C}$		175		ns
$t_f$	$R_{Gon} = R_{Goff} = 120\text{ Ω}$		60		ns
$E_{on}$	inductive load		0,22		mJ
$E_{off}$			0,12		mJ
<b>Diode - Inverter, Chopper</b>					
$V_F = V_{EC}$	$I_F = 6\text{ A}$ , $T_j = 25\text{ (125) °C}$		1,3 (1,3)	1,6 (1,6)	V
$V_{(TO)}$	$T_j = 25\text{ (150) °C}$		0,9 (0,8)	1 (0,9)	V
$r_T$	$T_j = 25\text{ (1150) °C}$		67 (83)	100 (117)	mΩ
$R_{th(j-s)}$	per diode		3		K/W
$I_{RRM}$	under following conditions		11,2		A
$Q_{rr}$	$I_F = 6\text{ A}$ , $V_R = 300\text{ V}$		0,9		μC
$E_{rr}$	$V_{GE} = 0\text{ V}$ , $T_j = 125\text{ °C}$		0,19		mJ
	$di_F/dt = 520\text{ A/μs}$				
<b>Diode - Rectifier</b>					
$V_F$	$I_F = 15\text{ A}$ , $T_j = 25\text{ °C}$		1,1		V
$V_{(TO)}$	$T_j = 150\text{ °C}$		0,8		V
$r_T$	$T_j = 150\text{ °C}$		20		mΩ
$R_{th(j-s)}$	per diode		1,5		K/W
<b>Temperature Sensor</b>					
$R_{ts}$	3 %, $T_r = 25\text{ (100) °C}$		1000(1670)		Ω
<b>Mechanical Data</b>					
w			21,5		g
$M_s$	Mounting torque	2		2,5	Nm



This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.